

Quantum Physics 1

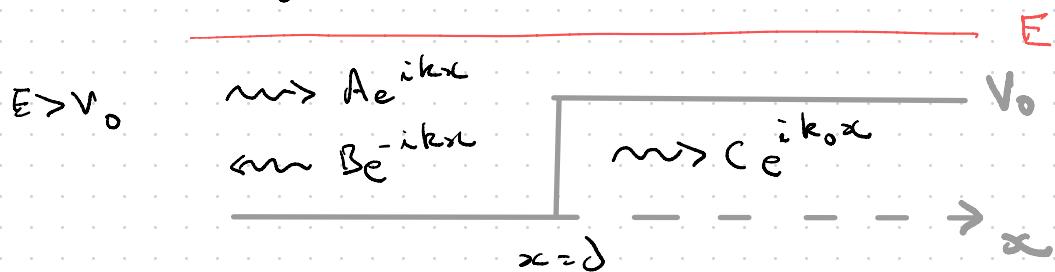
Class 16

Class 16

Quantum Tunneling

Last time :

Scattering from a Step Potential

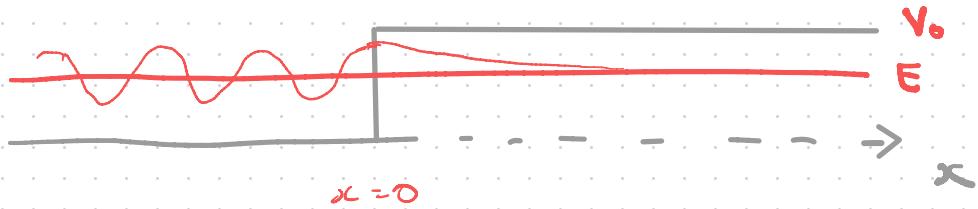


Consider the probability flux \bar{J} :

$$\left. \begin{aligned} \bar{J}_A &= \frac{\hbar k}{m} A A^+ \\ \bar{J}_B &= -\frac{\hbar k}{m} B B^+ \\ \bar{J}_C &= \frac{\hbar k_0}{m} C C^+ \end{aligned} \right\} \begin{array}{ll} x < 0 & k = \sqrt{\frac{2mE}{\hbar^2}} \\ x > 0 & k_0 = \sqrt{\frac{2m(E-V_0)}{\hbar^2}} \end{array}$$

Can calculate R & T .

For the case $E < V_0$



$$\text{for } \alpha > 0 : k_0 = \sqrt{\frac{2m(E - V_0)}{\hbar^2}}$$

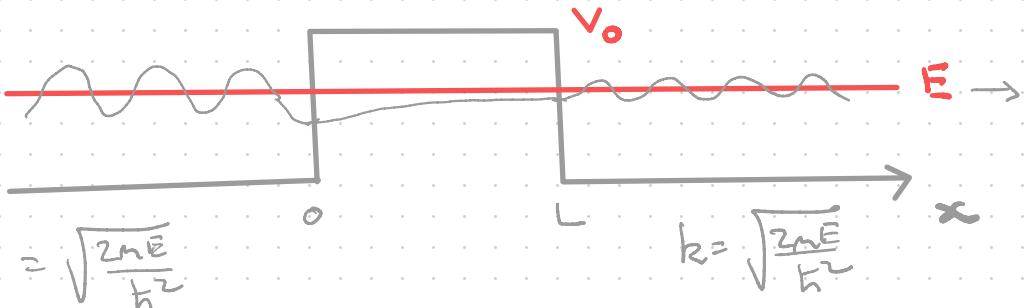
$$= i \sqrt{\frac{2m(V_0 - E)}{\hbar^2}}$$

$$= i k$$

w/t solutions:

$$\text{in RHS: } e^{ik_0 x} = e^{-k x};$$

Now in the case of finite barriers, if the width of the barrier \ll decay of Ψ then the Ψ can "escape" or "tunnel" to the RHS from the LHS.



$$k = \sqrt{\frac{2mE}{\hbar^2}}$$

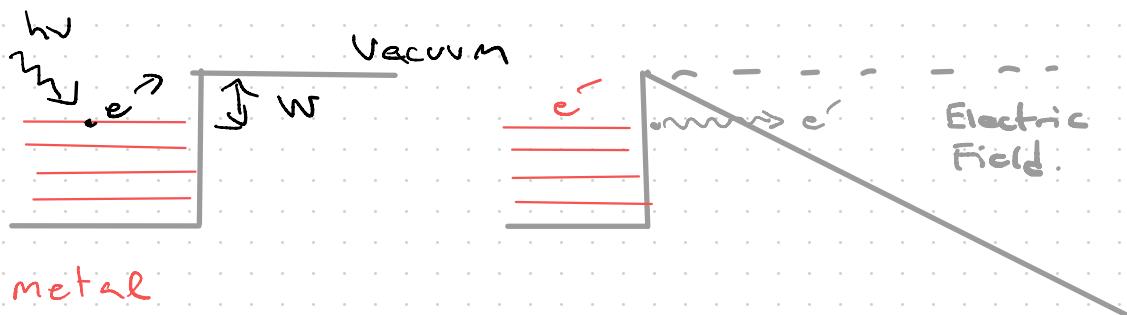
$$k = \sqrt{\frac{2mE}{\hbar^2}}$$

Q.B : The amount of tunneling depends on the height and the width of the barrier, $V_0 > L$.

Applications?

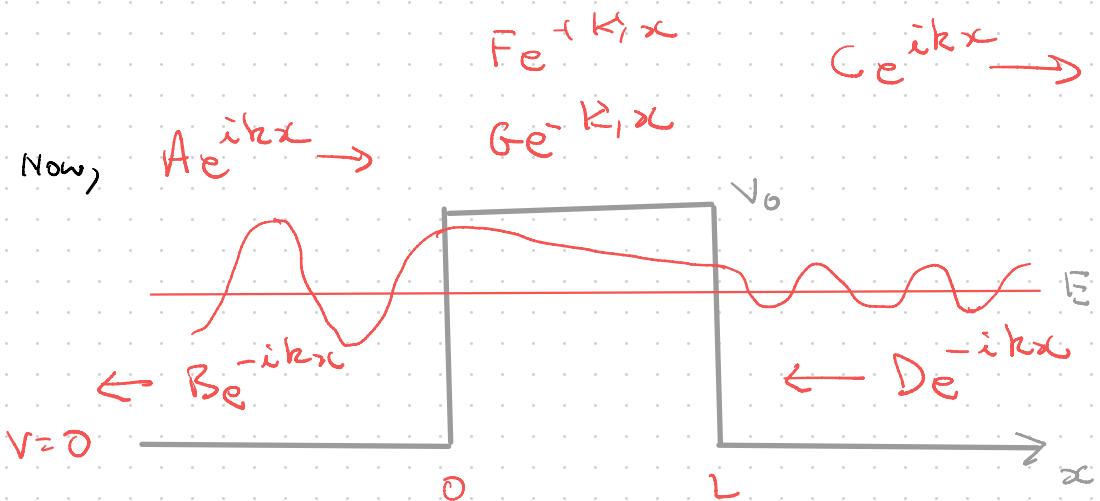
- ① Scanning Tunneling Microscopy (STM)
- ② Field emission Scanning electron microscopy, cold emission (CSEM).
- ③ α -decay.

Recall Photoelectric effect:-



In-class # (6-)

Now let's consider the finite barrier as a scattering problem. With an incident wave coming from the left hand side (LHS).



$$x < 0 : A e^{i k_1 x} + B e^{-i k_1 x}$$

$$0 < x < L : F e^{i k_1 x} + G e^{-i k_1 x}$$

$$x > L : C e^{i k_1 x} + D e^{-i k_1 x}$$

$$T = \frac{|C|^2}{|A|^2} = \left(1 + \frac{(k^2 + k_{\perp}^2)^2}{4 k^2 k_{\perp}^2} \sinh^2(k_{\perp} L) \right)^{-1}$$

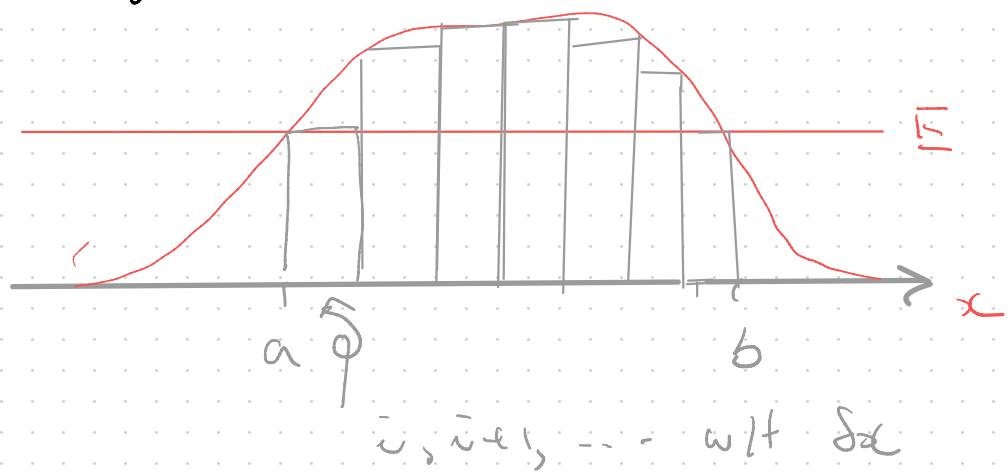
$$\text{where } \sinh(k_{\perp} L) = \frac{e^{k_{\perp} L} - e^{-k_{\perp} L}}{2}$$

for $k_1 L \gg 1$; $\sinh(k_1 L) \approx \frac{1}{2} e^{k_1 L}$

$$T = \left(\frac{4 k_1 k_f}{k_f^2 + k_1^2} \right)^2 e^{-2 k_1 L}$$

In-class 16.2, 16.3, 16.4

Consider potential barrier with an arbitrary shape :



$$T = 16 \frac{E}{V_0} \left(1 - \frac{E}{V_0}\right) e^{-2K_1 L}$$

$$\ln T = \text{const} - 2K_1 L ; \text{ wlt } 2K_1 L \gg \text{const.}$$

Now, $\ln T = \ln \prod_i T_i = \sum_i \ln T_i$

$$= -2 \sum_i K_{1i} Sx$$

occult:

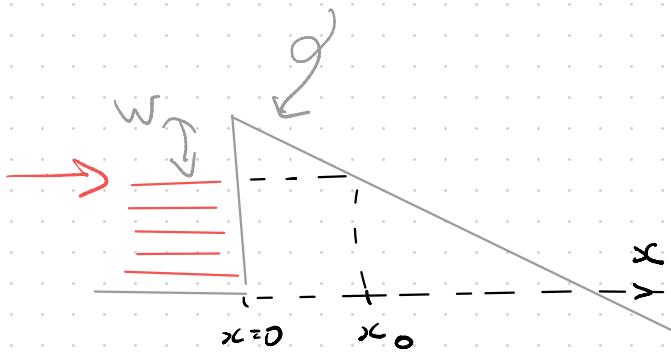
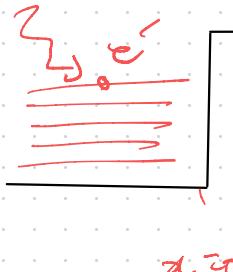
$$\ln(A \cdot B) = \ln A + \ln B.$$

$$\therefore T \approx C e^{-2 \sum_i K_{1i} Sx}$$

$$\bar{T} \approx C e^{-2 \int_a^b dx \sqrt{\frac{2m(V_0 - E)}{\hbar^2}}}$$

MB: There are many instances where we need to consider a barrier that's not rectangular:

$$W = 0$$



{Recall: Electric field, E_0 w/t $V = qE_0x$ }

$$\text{Now, } E = W + E - eE_0x_0$$

$$0 = W - eE_0x_0$$

$$x_0 = W/eE_0$$

So,

$$T \approx Ce^{\frac{-2\int dx}{\hbar^2} \sqrt{\frac{2m}{\hbar^2}(W - eE_0x)}}$$
$$\approx Ce^{-\left(\frac{4}{3\hbar}\right)\sqrt{2m/E_0}W^{3/2}}$$


Fowler-Nordheim
Relationship.